TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX138F,TC74LVX138FN,TC74LVX138FT

3-to-8 Line Decoder

The TC74LVX138F/ FN/ FT is a high-speed CMOS 3-to-8 line decoder fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

When the device is enabled, 3 Binary Select inputs (A, B and C) determine which one of the outputs $(\overline{Y}0-\overline{Y}7)$ will go low. When enable input G1 is held low or either $\overline{G}2A$ or $\overline{G}2B$ is held high, decoding function is inhibited and all outputs go high.

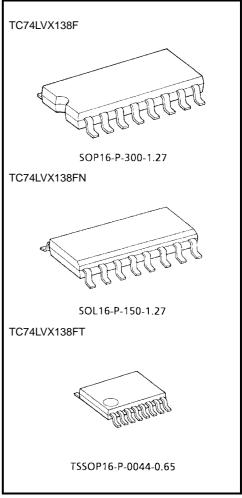
G1, $\overline{G}2A$, and $\overline{G}2B$ inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

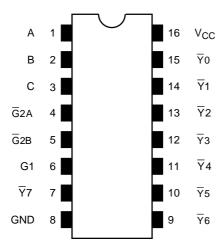
- High-speed: $t_{pd} = 5.5 \text{ ns (typ.) (VCC} = 3.3 \text{ V)}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max) (Ta} = 25 ^{\circ}\text{C)}$
- Input voltage level: $V_{IL} = 0.8 \text{ V (max)} (V_{CC} = 3 \text{ V})$ $V_{IH} = 2.0 \text{ V (min)} (V_{CC} = 3 \text{ V})$
- Power-down protection provided on all inputs
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Pin and function compatible with 74HC138

Note: xxxFN (JEDEC SOP) is not available in Japan.

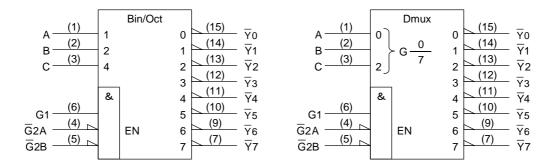


Weight SOP16-P-300-1.27: 0.18 g (typ.) SOL16-P-150-1.27: 0.12 g (typ.) TSSOP16-P-0044-0.65: 0.06 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol

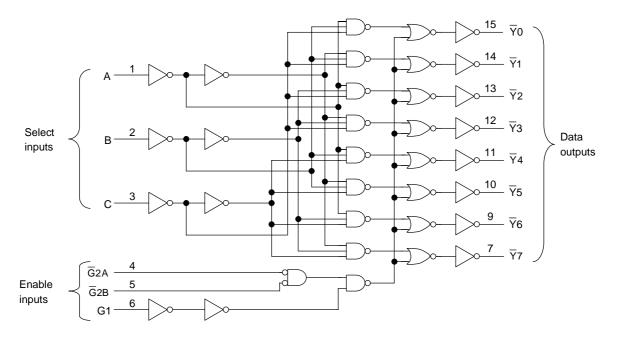


Truth Table

	Inputs						Outputs								
Enable		Select		_ Y0	0 <u>Y</u> 1	_ Y2	- Y3	<u>-</u> Y4	_ Y5	<u>7</u> 6		Selected Output			
G1	G2A	G ₂ B	C	В	Α	10	10 11	11 12	13	14	13	10	1 /		
L	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None	
Х	Н	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None	
Х	Х	Н	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None	
Н	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	₹0	
Н	L	L	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	₹1	
Н	L	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н	Ÿ2	
Н	L	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н	Y 3	
Н	L	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н	Y 4	
Н	L	L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н	Ÿ5	
Н	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	₹6	
Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L	Ÿ7	

X: Don't care

System Diagram



Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
DC output voltage	V _{OUT}	-0.5 to V_{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	±20	mA
DC output current	l _{OUT}	±25	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65 to 150	°C

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0 to 3.6	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V



Electrical Characteristics

DC Characteristics

Character	Symbol Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit		
					V _{CC} (V)	Min	Тур.	Max	Min	Max	
					2.0	1.5	_	_	1.5	_	
	H-level	V _{IH}	_		3.0	2.0	_	_	2.0	_	
Input voltago					3.6	2.4	_	_	2.4	_	0.8
Input voltage					2.0 —		_	0.5	_	0.5	V
	L-level	V _{IL}		_	3.0	_	_	0.8	_	0.8	
					3.6	_	_	0.8	_	0.8	
			V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -50 \mu A$	2.0	1.9	2.0	_	1.9	_	
	H-level	V _{OH}		$I_{OH} = -50 \mu A$	3.0	2.9	3.0	_	2.9	_	
Output voltage				$I_{OH} = -4 \text{ mA}$	3.0	2.58	_	_	2.48	_	V
Output voltage				$I_{OL} = 50 \mu A$	2.0	_	0	0.1	_	0.1	V
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	$I_{OL} = 50 \mu A$	3.0	_	0	0.1	_	0.1	
				I _{OL} = 4 mA	3.0	_	_	0.36	_	0.44	
Input leakage curr	I _{IN}	V _{IN} = 5.5 V or GND		3.6	_	_	±0.1	_	±1.0	μΑ	
Quiescent supply	Icc	V _{IN} = V _{CC} or GND		3.6	_		4.0	_	40.0	μΑ	

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	ndition		Ta = 25°C		Ta = -40 to 85°C		Unit		
			V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max		
	+		2.7	15	_	7.1	13.8	1.0	16.5	ns	
Propagation delay time	t _{pLH}		2.1	50	_	9.6	17.3	1.0	20.0		
(A, B, C- \overline{Y})	+	_	3.3 ± 0.3	15	_	5.5	8.8	1.0	10.5		
	t _{pHL}		ა.ა ± 0.ა	50	_	8.0	12.3	1.0	14.0		
	+		2.7 15 50	15	_	8.7	16.3	1.0	19.5		
Propagation delay time	t _{pLH}			_	11.2	19.8	1.0	23.0	ns		
(G1- \overline{Y})	+	_	3.3 ± 0.3	15	_	6.8	10.6	1.0	12.5	-	
	t _{pHL}			50	_	9.3	14.1	1.0	16.0		
	t _{pLH}		2.7	15	_	8.8	16.0	1.0	18.5	ns	
Propagation delay time				50	_	11.3	19.5	1.0	22.0		
(G 2 - Y)		_	3.3 ± 0.3	15	_	6.9	10.4	1.0	11.5		
	t _{pHL}			50	_	9.4	13.9	1.0	15.0		
Output to output skew	t _{osLH}	(Note 1)	2.7	50		_	2.5	_	2.5	ns	
Output to output skew	t _{osHL}		3.3 ± 0.3	50			2.5		2.5	113	
Input capacitance	C _{IN}			(Note 2)		4	10	_	10	pF	
Power dissipation capacitance	C_{PD}			(Note 3)	_	34	_	_		pF	

Note 1: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$

Note 2: Parameter guaranteed by design.

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

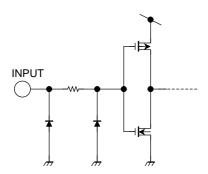
 $I_{CC \text{ (opr)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3$ ns, $C_L = 50$ pF)

Characteristics		Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic	V_{OL}	V _{OLP}	_	3.3	_	0.5	V
Quiet output minimum dynamic	V_{OL}	V _{OLV}	_	3.3	_	-0.5	V
Minimum high level dynamic input voltage	V _{IH}	V _{IHD}	_	3.3	_	2.0	V
Maximum low level dynamic input voltage	V _{IL}	V _{ILD}	_	3.3	_	0.8	V

Input Equivalent Circuit

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Package Dimensions

SOP16-P-300-1.27

Unit:mm

16
9
0.705TYP

10.8MAX

10.3±0.2

10.8MAX

10.3±0.2

10.8MAX

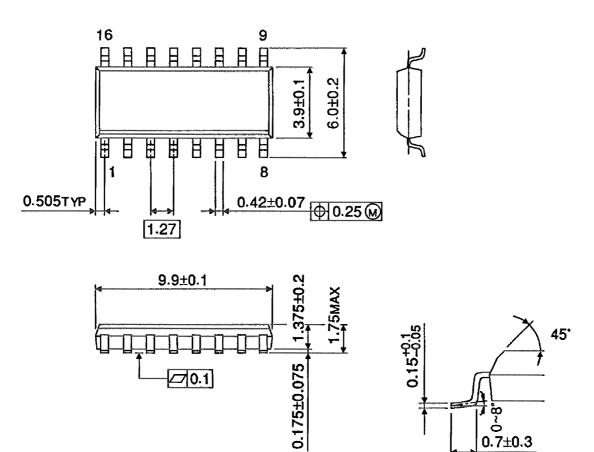
Weight: 0.18 g (typ.)

⊘ 0.1

0.8±0.2

Package Dimensions

SOL16-P-150-1.27 Unit: mm



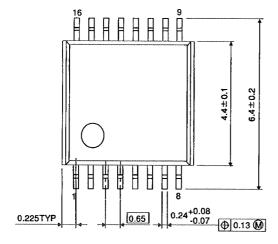
Weight: 0.12 g (typ.)

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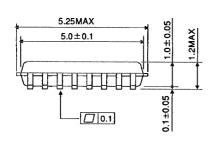
Unit: mm

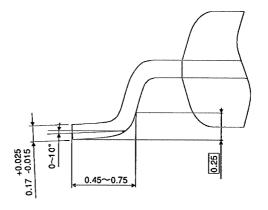
Package Dimensions

TSSOP16-P-0044-0.65









Weight: 0.06 g (typ.)

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